

## isc N-Channel MOSFET Transistor

# IRFP4004, IIRFP4004

#### FEATURES

• Static drain-source on-resistance: R<sub>DS</sub>(on)≤1.7mΩ

- Enhancement mode: Vth =2.0 to 4.0V (Vps=Vgs, Ip=250 μ A)
- 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

#### DESCRITION

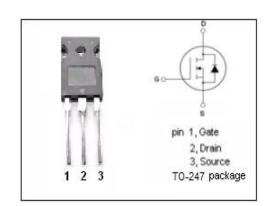
- High Efficiency Synchronous Rectification in SMPS
- Uninterruptible Power Supply
- · High Speed Power Switching

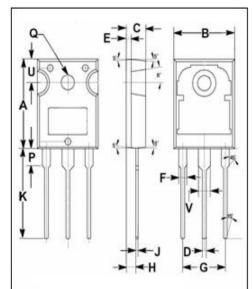
### • ABSOLUTE MAXIMUM RATINGS(Ta=25°C)

SYMBOL	PARAMETER	VALUE	UNIT	
V <sub>DSS</sub>	Drain-Source Voltage	40	V	
V <sub>GS</sub>	Gate-Source Voltage	±20	V	
I <sub>D</sub>	Drain Current-Continuous	195	A	
I <sub>DM</sub>	Drain Current-Single Pulsed	1390	А	
P <sub>D</sub>	Total Dissipation @T <sub>c</sub> =25℃	380	W	
Tj	Max. Operating Junction Temperature	175	${\mathbb C}$	
T <sub>stg</sub>	Storage Temperature	-55~175	${\mathbb C}$	

#### • THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	MAX	UNIT
Rth(j-c)	Channel-to-case thermal resistance	0.4	°C/W
Rth(j-a)	a) Channel-to-ambient thermal resistance		°C/W





	mm			
DIM	MIN	MAX		
Α	19.80	20.20		
В	15.40	15.80		
C	4.90	5.10		
D	0.90	1.10		
E	1.40	1.60		
F	1.90	2.10		
G	10.80	11.00		
Н	2.40	2.60		
J	0.50	0.70		
K	19.50	20.50		
P	3.90	4.10		
Q	3.30	3.50		
U	5.20	5.40		
٧	2.90	3.10		



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#### **ELECTRICAL CHARACTERISTICS**

T<sub>c</sub>=25℃ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	ТҮР	MAX	UNIT
BV <sub>DSS</sub>	Drain-Source Breakdown Voltage	V <sub>GS</sub> =0V; I <sub>D</sub> =250 μ A	40			V
$V_{\text{GS(th)}}$	Gate Threshold Voltage	VDS=VGS; I <sub>D</sub> =250 μ A	2.0		4.0	V
R <sub>DS(on)</sub>	Drain-Source On-Resistance	V <sub>GS</sub> =10V; I <sub>D</sub> =195A			1.7	mΩ
I <sub>GSS</sub>	Gate-Source Leakage Current	V <sub>GS</sub> = ±20V			±0.2	μ <b>А</b>
I <sub>DSS</sub>	Drain-Source Leakage Current	V <sub>DS</sub> =40V; V <sub>GS</sub> = 0V			20	μА
V <sub>SD</sub>	Diode forward voltage	I <sub>S</sub> =195A, V <sub>GS</sub> = 0V			1.3	V

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